



GPY0033A

PWM Amplifier with Audio Mixer

Jan 31, 2013 Version 1.0



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PWM AMPLIFIER WITH AUDIO MIXER

1. GENERAL DESCRIPTION

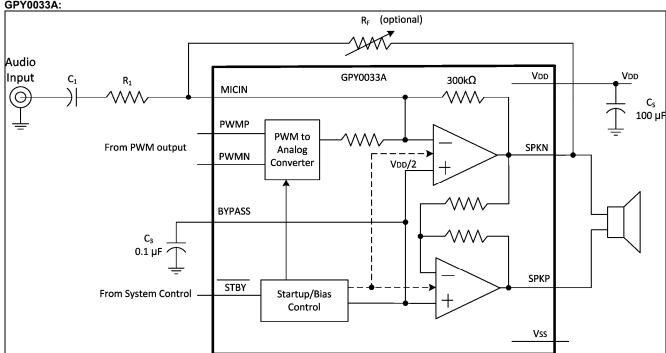
The GPY0033A is an audio amplifier, designed especially for PWM signal. It can accept PWM signal directly without any external device. In addition, it also provides a channel for analog signal to mix with the PWM signal; that is, the sound of microphone is easy to work with the PWM sound. GPY0033A is also built in the anti-pop circuit to minimize the turn-on and turn-off pop noise. Normally, it is applied for GPC series, GPF series, GPL series and other GENERALPLUS products. The GPY0033A is easily to be used in various applications and products

2. FEATURES

- Wide Operation Range: 2.4V 5.5V
- Bridge-Tied Load (BTL)
- Low Distortion: THD+N < 1% (Typ.) (For VDD = 5.0V, R_L = 8.0 Ω & P_{out} = 800mW)
- High Output Power: P_{OUT} > 0.8W (For VDD = 5.0V, THD+N =1.0%, f =1.0KHz & $R_L = 8\Omega$)
- Low Shutdown Current: < 1.0µA
- Low Supply Current
- Minimize the turn-on and turn-off pop noise
- Fast Startup Time

3. BLOCK DIAGRAM

GPY0033A:



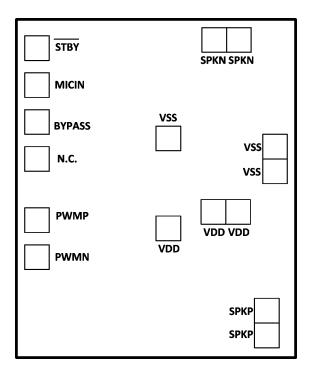


4. SIGNAL DESCRIPTIONS

GPY0033A:

Mnemonic	PIN No.	Type	Description	Electrical Characteristics
STBY	2	I	Standby control, low active. An internal resistor is pulled to ground weakly	-
MICIN	3	1	Channel for analog signal input	-
BYPASS	4	0	Reference voltage for OP positive terminal, a 0.1uF capacitor is necessary	VDD/2
PWMP	5	1	PWM positive terminal. An internal resistor is pulled to ground weakly when STBY is high.	-
PWMN	6	1	PWM negative terminal. An internal resistor is pulled to ground weakly when STBY is high.	-
SPKP	9	0	The positive terminal for speaker	-
VDD	10	1	Power VDD	2.4V – 5.5V
VSS	12	I	Power Ground	-
SPKN	13	0	The negative terminal for speaker	-

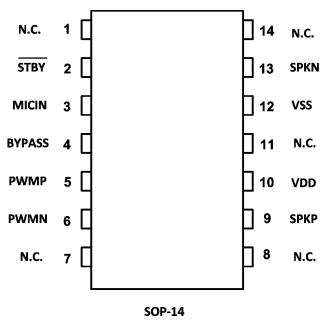
4.1. PAD Assignment



The IC substrate should be connected to VSS



4.2. Package Pin Assignment



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5. ELECTRICAL SPECIFICATIONS

5.1. Absolute Maximum Ratings

Characteristics	Symbol	Ratings
DC Supply Voltage	V ₊	< 5.5V
Input Voltage Range	V_{IN}	-0.5V to V+ + 0.5V
Operating free-air Temperature Range	T _A	-40°C to + 85°C
Operating junction Temperature Range	$T_\mathtt{J}$	-40°C to + 150°C
Storage Temperature	T _{STO}	-50°C to + 150°C

Note: Stresses beyond those given in the Absolute Maximum Rating table may cause permanent damage to the device. For normal operational conditions see AC/DC Electrical Characteristics.

5.2. Thermal Characteristics

Characteristics	Symbol	Value	Unit	
SOP-14 Package Thermal Resistance	R _{THJA}	90	°C/W	

5.3. DC Characteristics (V_{DD} =5.0V, T_A = 25°C unless otherwise specified)

GPY0033A:

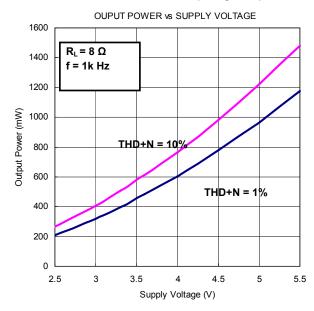
Item	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Operation Voltage	Temperature = 25°C	V_{DD}	2.4	1	5.5	V
Shutdown Current	STBY=GND	I _{STBY}	-	0.2	1.0	uA
Operating Current	$V_{DD} = 5.5V$, $\overline{STBY} = V_{DD}$, No Load	I _{DD}	-	3.5	5.5	mA
	V _{DD} = 2.4V~3.3V		0.5*V _{DD}	-	-	V
Input High Voltage	V _{DD} = 3.3V~5.5V	V _{IH}	0.45*V _{DD}	-	-	
	V _{DD} = 2.4V~3.3V		-	-	0.3*V _{DD}	.,
Input High Voltage	V _{DD} = 3.3V~5.5V	V _{IL}	-	-	0.25*V _{DD}	V
Total Harmonic Distortion +	V_{DD} = 5.0V, R_L = 8.0 Ω , P_{OUT} = 500mW	TUDIN		0.0		0/
Noise	f = 1.0KHz, R_F =33kΩ, R_I =30kΩ	THD+N	-	0.2	-	%
	V _{DD} = 5.0V, THD+N = 1%,					
	$f = 1.0KHz$, $R_L = 8.0\Omega$,	P _{OUT}	-	900	-	mW
Output Power	R_F =33k Ω , R_I =30k Ω					
(From MICIN)	V _{DD} = 5.0V, THD+N = 10%					
	$f = 1.0KHz$, $R_L = 8.0\Omega$,	P _{OUT}	-	1200	-	mW
	R_F =33k Ω , R_I =30k Ω					
Output Offset Voltage	V _{IN} =0V	Vos	-	-	30	mV
Enable Time	V _{DD} = 5.0V, C3=0.1μF,	T _{ON}	-	-	20	ms
Shutdown Time	V _{DD} = 5.0V, C3=0.1μF,	T _{OFF}	-	_	70	ms



5.4. Typical Performance Characteristics

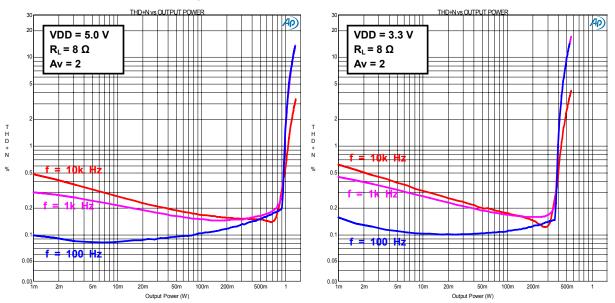
5.4.1. Output Power vs. Supply Voltage

Condition: R_F = 33k Ω , R_1 =30k Ω , C_1 =2.2 μ F, signal input from MICIN



5.4.2. THD+N (from MICIN)

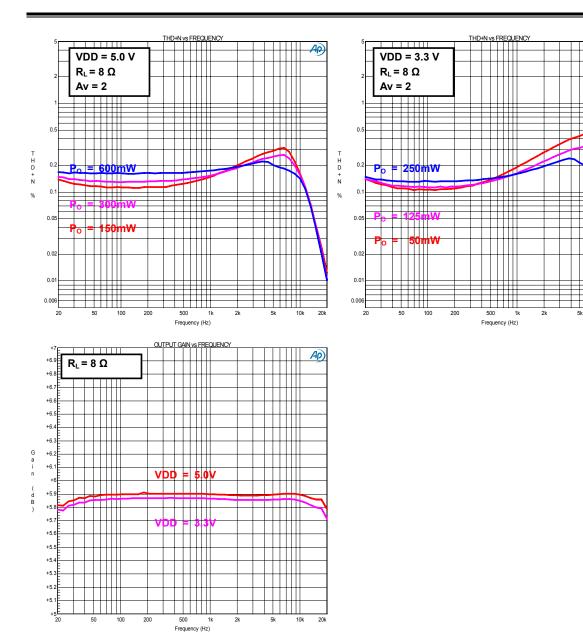
Condition: $R_F = 33k\Omega$, $R_1=30k\Omega$, $C_1=2.2\mu F$





Ap



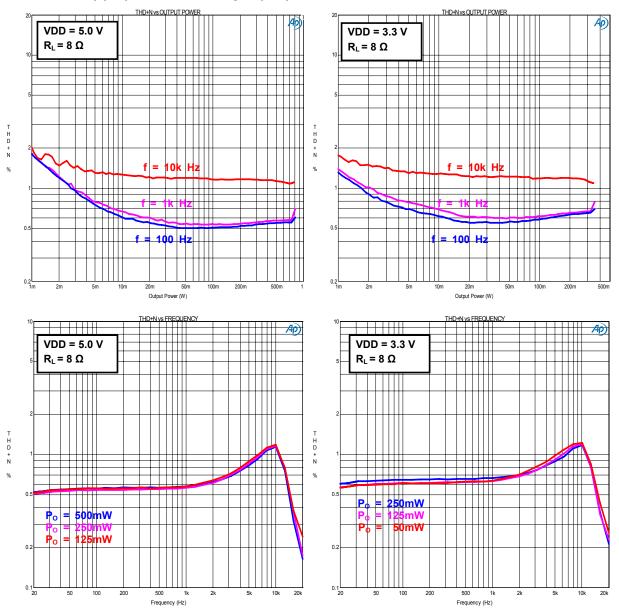




5.4.3. THD+N (from PWM)

Condition: PWM signal → 2nd delta-sigma modulation, 6.144 MHz clock rate and 96 KHz sample rate

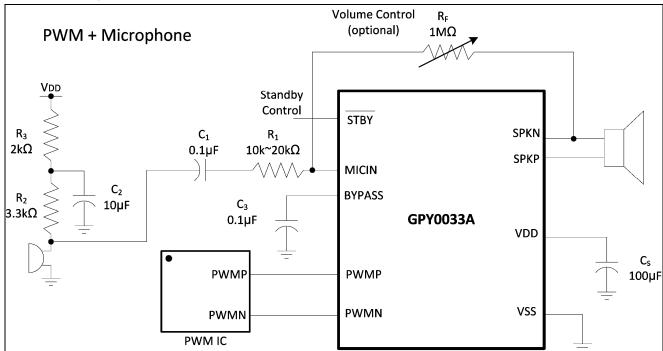
♦ THD+N deeply depends on the PWM signal quality





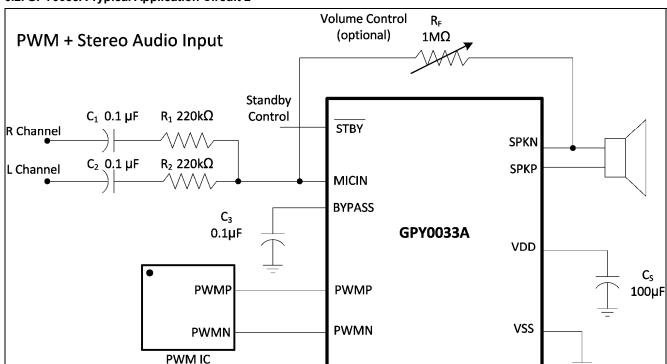
6. APPLICATION INFORMATION

6.1. GPY0033A Typical Application Circuit 1



• R_F is for volume control, the microphone gain = $(R_F//300k\Omega)/R_{1}$; the internal resistance between MICIN and SPKN is approx. $300k\Omega$.

6.2. GPY0033A Typical Application Circuit 2

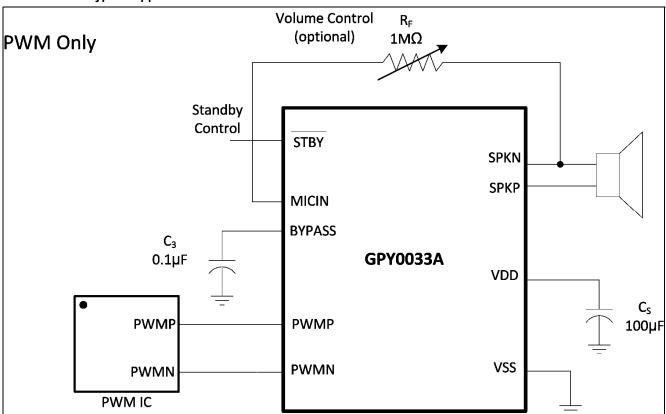


• R_F is for volume control, the audio input gain = $(R_F//300k\Omega)/R_1$; the internal resistance between MICIN and SPKN is approx. $300k\Omega$.

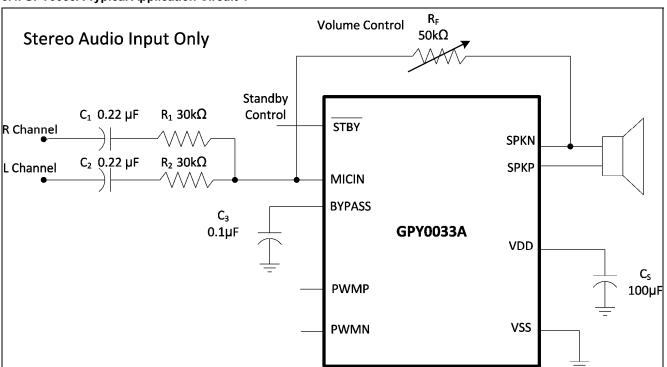
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6.3. GPY0033A Typical Application Circuit 3



6.4. GPY0033A Typical Application Circuit 4



• R_F is for volume control, the audio input gain = $(R_F//300k\Omega)/R_1$; the internal resistance between MICIN and SPKN is approx. $300k\Omega$.



7. PACKAGE/PAD LOCATIONS

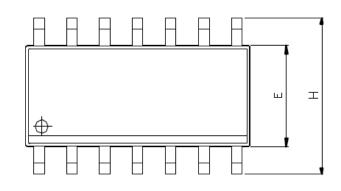
7.1. Ordering Information

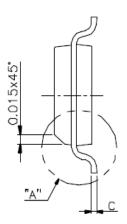
Product Number	Package Type		
GPY0033A - C	Chip form		
GPY0033A - HS02x	Green Package – SOP-14 (150mil)		

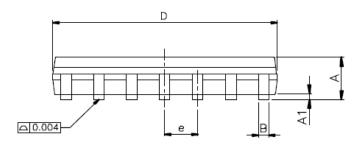
Note: Package form number (x = 1 - 9, serial number).

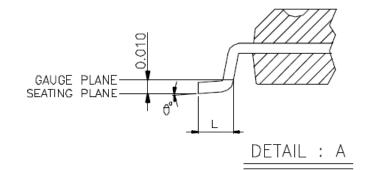
7.2. Package Information

7.2.1. SOP-14









Ownshall		Dimension in inch			
Symbol	Min.	Тур.	Max.		
Α	0.058	0.064	0.068		
A1	0.004	-	0.010		
В	0.13	0.016	0.020		
C	0.0075	0.008	0.0098		





Sumb al		Dimension in inch			
Symbol	Min.	Тур.	Max.		
D	0.336	0.341	0.344		
E	0.150	0.154	0.157		
е	-	0.050	0.050		
Н	0.228	0.236	0.244		
L	0.015	0.025	0.050		
θ°	0	-	8		



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9. REVISION HISTORY

Date	Revision #	Description	Page
Jan 31, 2012	1.0	Modify the maximum operating current.	15
Sep 06, 2012	0.3	Preliminary version	15

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